

AMPLIFIER A757 for LF706 and AMPLIFIER A757 for LF758/R - LF760/R

Resistors

R 1-R101	=	330	K Ω \pm 10%	0,5 W	269.3035.4
R 2-R102	=	5,6	K Ω \pm 10%	0,5 W	269.3023.4
R 3-R103	=	10	K Ω \pm 10%	0,5 W	269.3025.4
R 4-R104	=	10	K Ω \pm 10%	0,5 W	269.3025.4
R 5-R105	=	1	K Ω \pm 10%	0,5 W	269.3016.9
R 6-R106	=	8,2	K Ω \pm 5%	0,5 W	269.3024.6
R 7-R107	=	47	Ω \pm 5%	0,5 W	269.3005.3
R 8-9108	=	47	K Ω \pm 10%	0,5 W	269.3031.4
R 9-R109	=	47	K Ω \pm 10%	0,5 W	269.3031.4
R10-R110	=	2,2	K Ω \pm 5%	0,5 W	269.3019.8
R11-R111	=	27	K Ω \pm 5%	0,5 W	269.3029.8
R12-R112	=	1,5	K Ω \pm 5%	0,5 W	269.3018.2
R13-R113	=	8,2	K Ω \pm 5%	0,5 W	269.3024.6
R14-R114	=	27	K Ω \pm 5%	0,5 W	269.3029.8
R15-R115	=	390	Ω \pm 5%	0,5 W	269.3013.1
R16-R116	=	180	Ω \pm 5%	0,5 W	269.3010.3
R17-R117	=	470	Ω \pm 10%	0,5 W	269.3014.1
R18-R118	=	2,2	Ω \pm 10%	0,5 W	269.3000.3
R19-R119	=	2,2	Ω \pm 10%	0,5 W	269.3000.3
R20	=	5,6	K Ω \pm 10%	0,5 W	269.3023.4

Capacitors

C 1-C101	=	5	μ F	—	25 Vn Electrolytic	267.9001.4
						or	267.9001.3
C 3-C103	=	5	μ F	—	25 Vn Electrolytic	267.9001.4
						or	267.9001.3
C 4-C104	=	2,2	nF	\pm 10%	500 Vn Ceramic	267.6002.6
C 5-C105	=	10	nF	\pm 10%	125 Vn Synthetic	268.1004.7
						or	268.1004.1
C 6-C106	=	22	nF	\pm 10%	125 Vn Synthetic	268.1005.5
C 7-C107	=	100	nF	\pm 10%	125 Vn Synthetic	268.1007.8
C 8-C108	=	470	pF	\pm 10%	500 Vn Ceramic	267.7001.6
						or	267.6001.9
C 9-C109	=	33	nF	\pm 10%	125 Vn Synthetic	268.1006.2
C10-C110	=	470	nF	\pm 20%	125 Vn Synthetic	268.1009.5
C11-C111	=	250	μ F	—	3 Vn Electrolytic	267.9008.9
						or	267.9008.7
C12-C112	=	100	μ F	—	3 Vn Electrolytic	267.9006.2
						or	267.9006.0
C13-C113	=	100	μ F	—	3 Vn Electrolytic	267.9006.2
						or	267.9006.0
C14-C114	=	100	μ F	—	12 Vn Electrolytic	267.9007.4
C15-C115	=	1000	μ F	—	12 Vn Electrolytic	267.9010.9
C16	=	2000	μ F	—	25 Vn Electrolytic	267.9011.4
C17	=	250	μ F	—	12 Vn Electrolytic	267.9009.6
						or	267.9009.4

Controls

P1-P101	=	} 9B14/A+9B14/A	100 K Ω +100 K Ω c.u.	Dm 18066/36
P2-P102	=				
P3-P103	=	9B14/0+9B14/DR	100 K Ω +100 K Ω c.u.	Dm 18066/37
P4-P104	=	9B14/A+9B14/A	100 K Ω c.p. 67 K Ω	Dm 18066/38
			+100 K Ω c.p. 67 K Ω c.c.	

Semiconductors

Tr1-Tr101	=	} SFT 337 MISTRAL	260.2027.0
Tr2-Tr102	=		or AT 210 - 6 A.T.E.S.
Tr3-Tr103	=	SFT 337/D MISTRAL	260.2024.0
		or AC 141/B A.T.E.S.	260.2021.0
Tr4-Tr104	=	AC 180 KD MISTRAL	260.2035.0
		or AC 138 K A.T.E.S.	260.2042.0
Tr5-Tr105	=	} Matched 1 x AC181K (NPN MISTRAL	260.2034.0
Tr6-Tr106	=		1 x AC180K (PNP MISTRAL	
		or Matched 1 x AC141K (NPN) A.T.E.S.	260.2043.0
		+1 x AC132K (PNP) A.T.E.S.	

AMPLIFIER A757 for LF706 Only

Rd1-Rd2	=	Silicon rectifiers 2E2 IRCI	260.1013.0
		or TR 05 or TR 05A RAYTHEON - ELSI	260.1019.0
D1-D101	=	PTO MISTRAL	260.1307.0
		or 10207 A.T.E.S.	260.2012.0

Miscellaneous

Automatic Record Changer	CN1/GW-Dia	950.1011.1
La	= Pilot lamp 24 V	263.4003.0
T1	= Power transformer	263.8024.0
SPKR1-SPKR101	- \emptyset 160	263.3009.1
		or	263.3016.0
SPKR2-SPKR102	- \emptyset 130	263.3008.1
C18-C118	= capacitors 2,2 μ F 250 Vcc \pm 10%	268.1011.5
C19	= capacitors 47 nF 600 Vn	268.1010.5
R22-R122	= resistors 100 K Ω \pm 10% 0,5 W	269.3032.6
R23-R123	= resistors 10 K Ω \pm 10% 0,5 W	269.3025.4
R21	= resistors 100 Ω \pm 10% 0,5 W	269.3007.3
F	= Fuse 0,5A	263.5001.1

INPUT SWITCH (Sw1) for LF706 Only

Resistors

R1-R101	=	150 K Ω \pm 5%	0,125 W	269.1019.0
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Capacitors

R2-R102	=	470 K Ω \pm 5%	0,125 W	269.1021.4
C1-C101	=	4,7 nF	600 Vn Ceramic	268.1003.0